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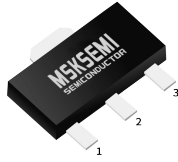
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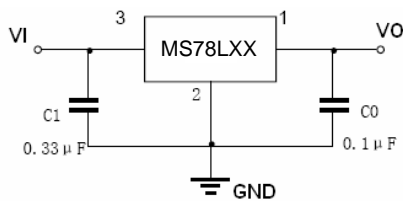
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Product data sheet

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SOT-89



FEATURES

- Wide range of available, fixed output voltage.
- Low cost.
- Internal short-circuit current limiting.
- Internal thermal overload protection.
- No external components required.
- Complementary negative regulators offered (79LXX series).

APPLICATIONS

- Three-terminal positive voltage regulator.

MAXIMUM RATING operating temperature range applies unless otherwise specified

Symbol	Parameter	Value	Units
V_I	Input voltage(3.3V-9V) (10V-15V) (18V-24V)	30 35 40	V
I_{CM}	Maximum output current	100	mA
P_D	Power dissipation	500	mW
T_{OPR}	Operating junction temperature	-40 to +125	°C
T_j, T_{stg}	Storage temperature range	-40 to +150	°C

ELECTRICAL CHARACTERISTICS

 ● **MS78L33** ($V_{IN}=10V, I_O=40mA, 0^{\circ}C < T < 125^{\circ}C, C_I=0.33\mu F, C_O=0.1\mu F$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L33			UNIT
			MIN	TYP	MAX	
Output voltage	V_O	$T_j=25^{\circ}C$ $5.3V \leq V_i \leq 20V, I_O=1mA-40mA$ $V_1=8.3V, I_O=1mA-70mA$	3.168 3.135 3.135	3.3	3.432 3.465 3.465	V
Load regulation	Reg_{load}	$T_j=25^{\circ}C, I_O=1mA-100mA$ $T_j=25^{\circ}C, I_O=1mA-40mA$			60 30	mV
Line regulation	Reg_{line}	$5.3V \leq V_i \leq 20V, T_j=25^{\circ}C$ $6.3V \leq V_i \leq 20V, T_j=25^{\circ}C$			150 100	mV
Input Bias Current	I_{IB}	$T_j=25^{\circ}C$ $T_j=125^{\circ}C$			6.0 5.5	mA
Input Bias Current Change	ΔI_{IB}	$6.3V \leq V_i \leq 20V$ $1mA \leq I_O \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$10Hz \leq f \leq 100KHz$		40		μV
Ripple rejection	RR	$I_O=40mA, 6.3V \leq V_i \leq 16.3V$ $f=120Hz, T_j=25^{\circ}C$	41	49		dB
Dropout voltage	V_I-V_O	$T_j=25^{\circ}C$		1.7		V

ELECTRICAL CHARACTERISTICS

 ● **MS78L05** ($V_{IN}=10V, I_O=40mA, 0^{\circ}C < T < 125^{\circ}C, C_I=0.33\mu F, C_O=0.1\mu F$, unless otherwise specified)

Parameter	Symbol	Test conditions	78L05			UNIT
			MIN	TYP	MAX	
Output voltage	V_O	$T_j=25^{\circ}C$ $7V \leq V_i \leq 20V, I_O=1mA-40mA$ $V_1=10V, I_O=1mA-70mA$	4.8 4.75 4.75	5.0	5.2 5.25 5.25	V
Load regulation	Reg_{load}	$T_j=25^{\circ}C, I_O=1mA-100mA$ $T_j=25^{\circ}C, I_O=1mA-40mA$		11 5	60 30	mV
Line regulation	Reg_{line}	$7V \leq V_i \leq 20V, T_j=25^{\circ}C$ $8V \leq V_i \leq 20V, T_j=25^{\circ}C$		55 45	150 100	mV
Input Bias Current	I_{IB}	$T_j=25^{\circ}C$ $T_j=125^{\circ}C$		3.8	6.0 5.5	mA
Input Bias Current Change	ΔI_{IB}	$8V \leq V_i \leq 20V$ $1mA \leq I_O \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$10Hz \leq f \leq 100KHz$		40		μV
Ripple rejection	RR	$I_O=40mA, 8V \leq V_i \leq 18V, f=120Hz$ $T_j=25^{\circ}C$	41	49		dB
Dropout voltage	V_I-V_O	$T_j=25^{\circ}C$		1.7		V

ELECTRICAL CHARACTERISTICS

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- MS78L06**
- (
- $V_{IN}=12V, I_O=40mA, 0^{\circ}C < T_J < 125^{\circ}C, C_I=0.33\mu F, C_O=0.1\mu F$
- , unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L06			UNIT
			MIN	TYP	MAX	
Output voltage	V_O	$T_J=25^{\circ}C$ $V_1=8.5V-20V, I_O=1mA-40mA$ $V_1=8.5V, I_O=1mA-70mA$	5.75 5.7 5.7	6.0	6.25 6.3 6.3	V
Load regulation	Reg_{load}	$T_J=25^{\circ}C, I_O=1mA-100mA$ $T_J=25^{\circ}C, I_O=1mA-70mA$		12.8 5.8	80 40	mV
Line regulation	Reg_{line}	$8.5V \leq V_i \leq 20V, T_J=25^{\circ}C$ $9V \leq V_i \leq 20V, T_J=25^{\circ}C$		64 54	175 125	mV
Input Bias Current	I_{IB}	$T_J=25^{\circ}C, V_{IN}=12V, I_O=40mA$ $T_J=125^{\circ}C, V_{IN}=12V, I_O=40mA$		3.9	5.5 6.0	mA
Input Bias Current Change	ΔI_{IB}	$9V \leq V_i \leq 20V$ $1mA \leq I_O \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$10Hz \leq f \leq 100KHz$		40		$\mu V/V_O$
Ripple rejection	RR	$I_O=40mA, 10V \leq V_i \leq 20V, f=120Hz,$ $T_J=25^{\circ}C$	40	46		dB
Dropout voltage	V_D	$T_J=25^{\circ}C$		1.7		V

ELECTRICAL CHARACTERISTICS

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- MS78L08**
- (
- $V_i=14V, I_O=40mA, 0^{\circ}C < T_J < 125^{\circ}C, C_I=0.33\mu F, C_O=0.1\mu F$
- , unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L08			UNIT
			MIN	TYP	MAX	
Output voltage	V_O	$T_J=25^{\circ}C$ $10.5V \leq V_i \leq 23V, I_O=1mA-40mA$ $V_1=14V, I_O=1mA-70mA$	7.7 7.6 7.6	8.0	8.3 8.4 8.4	V
Load regulation	Reg_{load}	$T_J=25^{\circ}C, I_O=1mA-100mA$ $T_J=25^{\circ}C, I_O=1mA-40mA$		15 8.0	80 40	mV
Line regulation	Reg_{line}	$10.5V \leq V_i \leq 23V, T_J=25^{\circ}C$ $11V \leq V_i \leq 23V, T_J=25^{\circ}C$		20 12	175 125	mV
Input Bias Current	I_{IB}	$T_J=25^{\circ}C$ $T_J=125^{\circ}C$		3	6.0 5.5	mA
Input Bias Current Change	ΔI_{IB}	$11V \leq V_i \leq 23V$ $1mA \leq I_O \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$T_A=25^{\circ}C, 10Hz \leq f \leq 100KHz$		60		μV
Ripple rejection	RR	$I_O=40mA, 12V \leq V_i \leq 23V, f=120Hz,$ $T_J=25^{\circ}C$	37	57		dB
Dropout voltage	V_i-V_O	$T_J=25^{\circ}C$		1.7		V

ELECTRICAL CHARACTERISTICS

 ● **MS78L09** ($V_I=15V, I_O=40mA, 0^\circ C < T_J < 125^\circ C, C_I=0.33\mu F, C_O=0.1\mu F$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L09			UNIT
			MIN	TYP	MAX	
Output voltage	V_O	$T_J=25^\circ C$ $V_I=11.5V-24V, I_O=1mA-40mA$ $V_I=15V, I_O=1mA-70mA$	8.6 8.5 8.5	9.0	9.4 9.5 9.5	V
Load regulation	Reg_{load}	$T_J=25^\circ C, I_O=1mA-100mA$ $T_J=25^\circ C, I_O=1mA-40mA$		15 8.0	90 40	mV
Line regulation	Reg_{line}	$11.5V \leq V_I \leq 24V, T_J=25^\circ C$ $12V \leq V_I \leq 24V, T_J=25^\circ C$		20 12	175 125	mV
Input Bias Current	I_{IB}	$T_J=25^\circ C$ $T_J=125^\circ C$		3.0	6.0 5.5	mA
Input Bias Current Change	ΔI_{IB}	$11V \leq V_I \leq 23V$ $1mA \leq I_O \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$T_A=25^\circ C, 10Hz \leq f \leq 100KHz$		60		μV
Ripple rejection	RR	$I_O=40mA, 13V \leq V_I \leq 24V, f=120Hz, T_J=25^\circ C$	37	57		dB
Dropout voltage	V_I-V_O	$T_J=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

 ● **MS78L10** ($V_{IN}=16V, I_O=40mA, C_{IN}=0.33\mu F, C_O=0.1\mu F, T_J=0$ to $125^\circ C$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L10			UNIT
			MIN	TYP	MAX	
Output voltage	V_O	$T_J=25^\circ C$	9.6	10	10.4	V
Load regulation(Note1)	ΔReg_{load}	$I_O = 1$ to $100mA, T_J = 25^\circ C$	-	17	90	mV
		$I_O = 1$ to $40mA, T_J = 25^\circ C$	-	9	45	mV
Line regulation(Note1)	ΔReg_{line}	$V_I = 12.5$ to $25V, T_J = 25^\circ C$	-	100	210	mV
		$V_I = 13$ to $25V, T_J = 25^\circ C$	-	90	160	mV
Input Bias Current	I_{IB}	$T_J = 25^\circ C$	-	2.0	3.0	mA
Input Bias Current Change	ΔI_{IB}	$V_I = 13$ to $25V, T_J = 25^\circ C$	-	-	1.0	mA
Output Noise Voltage	V_N	$10Hz \leq f \leq 100KHz$	-	70	-	μV
Ripple Rejection	RR	$V_I = 13$ to $23V, I_O = 40mA, f = 120Hz$	42	52	-	dB
Dropout Voltage	V_D	$T_J=25^\circ C$	-	1.7	-	V
Dropout voltage	V_I-V_O	$I_O = 5mA, T_J = 0$ to $125^\circ C$	-	0.9	-	mV/ $^\circ C$

ELECTRICAL CHARACTERISTICS

- **MS78L12** ($V_i=19V, I_o=40mA, 0^\circ C < T_j < 125^\circ C, C_i=0.33\mu F, C_o=0.1\mu f$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L12			UNIT
			MIN	TYP	MAX	
Output voltage	V_o	$T_j=25^\circ C$ $V_i=14.5V-27V, I_o=1mA-40mA$ $V_i=19V, I_o=1mA-70mA$	11.5 11.4 11.4	12	12.5 12.6 12.6	V
Load regulation	Reg_{load}	$T_j=25^\circ C, I_o=1mA-100mA$ $T_j=25^\circ C, I_o=1mA-40mA$		20 10	100 50	mV
Line regulation	Reg_{line}	$14.5V \leq V_i \leq 27V, T_j=25^\circ C$ $16V \leq V_i \leq 27V, T_j=25^\circ C$		120 100	250 200	mV
Input Bias Current	I_{IB}	$T_j=25^\circ C$ $T_j=125^\circ C$		4.2	6.5 6.0	mA
Input Bias Current Change	ΔI_{IB}	$16V \leq V_i \leq 27V$ $1mA \leq I_o \leq 40mA$			1.5 0.1	mA
Output Noise Voltage	V_N	$10Hz \leq f \leq 100KHz, T_A=25^\circ C$		80		μV
Ripple rejection	RR	$I_o=40mA, 15V \leq V_i \leq 25V, f=120Hz,$ $T_j=25^\circ C$	37	42		dB
Dropout voltage	V_i-V_o	$T_j=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

- **MS78L15** ($V_{IS}=23V, I_o=40mA, 0^\circ C < T_j < 125^\circ C, C_i=0.33\mu F, C_o=0.1\mu f$, unless otherwise specified)

Parameter	Symbol	Test conditions	MS78L15			UNIT
			MIN	TYP	MAX	
Output voltage	V_o	$T_j=25^\circ C$ $V_i=17.5V-30V, I_o=1mA-40mA$ $V_i=23V, I_o=1mA-70mA$	14.4 14.25 14.25	15	15.6 15.75 15.75	V
Load regulation	ΔReg_{load}	$T_j=25^\circ C, I_o=1mA-100mA$ $T_j=25^\circ C, I_o=1mA-40mA$		25 12	150 75	mV
Line regulation	ΔReg_{line}	$17.5V \leq V_i \leq 30V, T_j=25^\circ C$ $20V \leq V_i \leq 30V, T_j=25^\circ C$		130 110	300 250	mV
Input Bias Current	I_{IB}	$T_j=25^\circ C$ $T_j=125^\circ C$		4.4	6.5 6.0	mA
Input Bias Current Change	ΔI_{IB}	$20V \leq V_i \leq 30V$ $1mA \leq I_o \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$10Hz \leq f \leq 100KHz, T_A=25^\circ C$		90		μV
Ripple rejection	RR	$I_o=40mA, 18.5V \leq V_i \leq 28.5V,$ $f=120Hz, T_j=25^\circ C$	34	39		dB
Dropout voltage	V_i-V_o	$T_j=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

 ● **MS78L18** ($V_i=27V, I_o=40mA, 0^\circ C < T_j < 125^\circ C, C_i=0.33\mu F, C_o=0.1\mu f$, unless otherwise specified)

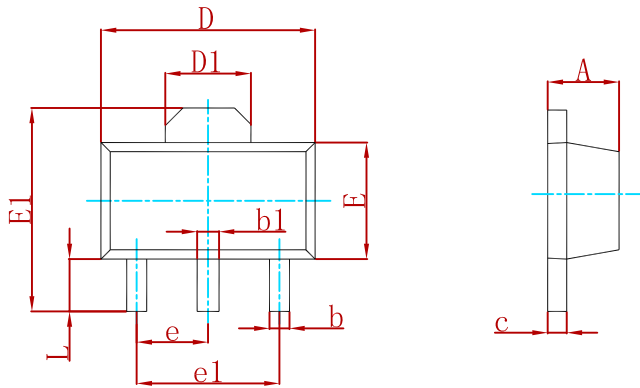
Parameter	Symbol	Test conditions	MS78L18			UNIT
			MIN	TYP	MAX	
Output voltage	V_o	$T_j=25^\circ C$ $V_i=20.7V-33V, I_o=1mA-40mA$ $V_i=27V, I_o=1mA-70mA$	17.3 17.1 17.1	18	18.7 18.9 18.9	V
Load regulation	Reg_{load}	$T_j=25^\circ C, I_o=1mA-100mA$ $T_j=25^\circ C, I_o=1mA-40mA$		30 15	170 85	mV
Line regulation	Reg_{line}	$20.7V \leq V_i \leq 33V, T_j=25^\circ C$ $21V \leq V_i \leq 33V, T_j=25^\circ C$		45 35	325 275	mV
Input Bias Current	I_{IB}	$T_j=25^\circ C$ $T_j=125^\circ C$		3.1	6.5 6.0	mA
Input Bias Current Change	ΔI_{IB}	$21V \leq V_i \leq 33V$ $1mA \leq I_o \leq 40mA$			1.5 0.1	mA
Output Noise Voltage	V_N	$10Hz \leq f \leq 100KHz, T_A=25^\circ C$		150		μV
Ripple rejection	RR	$I_o=40mA, 23V \leq V_i \leq 33V, f=120Hz,$ $T_j=25^\circ C$	33	48		dB
Dropout voltage	V_i-V_o	$T_j=25^\circ C$		1.7		V

ELECTRICAL CHARACTERISTICS

 ● **MS78L24** ($V_{IS}=33V, I_o=40mA, 0^\circ C < T_j < 125^\circ C, C_i=0.33\mu F, C_o=0.1\mu f$, unless otherwise specified)

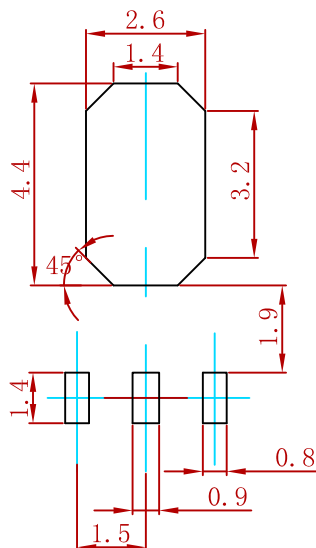
Parameter	Symbol	Test conditions	78L24			UNIT
			MIN	TYP	MAX	
Output voltage	V_o	$T_j=25^\circ C$ $V_i=27V-38V, I_o=1mA-40mA$ $V_i=27V-33V, I_o=1mA-70mA$	23 22.8 22.8	24	25 25.2 25.2	V
Load regulation	ΔReg_{load}	$T_j=25^\circ C, I_o=1mA-100mA$ $T_j=25^\circ C, I_o=1mA-40mA$		40 20	200 100	mV
Line regulation	ΔReg_{line}	$28V \leq V_i \leq 80V, T_j=25^\circ C$ $27V \leq V_i \leq 38V, T_j=25^\circ C$		50 60	300 350	mV
Input Bias Current	I_{IB}	$T_j=25^\circ C$ $T_j=125^\circ C$		3.1	6.5 6.0	mA
Input Bias Current Change	ΔI_{IB}	$28V \leq V_i \leq 38V$ $1mA \leq I_o \leq 40mA$			1.5 0.1	mA
Output noise voltage	V_N	$10Hz \leq f \leq 100KHz, T_A=25^\circ C$		200		μV
Ripple rejection	RR	$I_o=40mA, 29V \leq V_i \leq 35V,$ $f=120Hz, T_j=25^\circ C$	31	45		dB
Dropout voltage	V_i-V_o	$T_j=25^\circ C$		1.7		V

PACKAGE MECHANICAL DATA



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF.		0.061 REF.	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP.		0.060 TYP.	
e1	3.000 TYP.		0.118 TYP.	
L	0.900	1.200	0.035	0.047

Suggested Pad Layout



Note:
 1. Controlling dimension: in millimeters.
 2. General tolerance: $\pm 0.05\text{mm}$.
 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
MS78XX	SOT-89	1000

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